

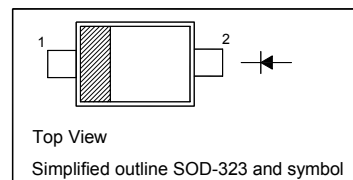
High Voltage Switching Diode

**Features**

- Fast switching speed
- Surface mount package ideally suited for automatic insertion

## PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode


**Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)**

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	120	V
		200	
		250	
Reverse Voltage	V <sub>R</sub>	100	V
		150	
		200	
Average Rectified Forward Current	I <sub>F(AV)</sub>	200	mA
Forward Continuous Current	I <sub>FM</sub>	400	mA
Repetitive Peak Forward Current	I <sub>FRM</sub>	625	mA
Non-Repetitive Peak Forward Surge Current	I <sub>FSM</sub>	at t = 1 μs 2.5	A
		at t = 1 s 0.5	
Power Dissipation	P <sub>tot</sub>	200	mW
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 65 to + 150	°C

**Characteristics at T<sub>a</sub> = 25 °C**

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at I <sub>R</sub> = 100 μA	V <sub>(BR)R</sub>	120	-	V
		200	-	
		250	-	
Reverse Current at V <sub>R</sub> = 100 V at V <sub>R</sub> = 150 V at V <sub>R</sub> = 200 V	I <sub>R</sub>	-	100	nA
		-	100	
		-	100	
Forward Voltage at I <sub>F</sub> = 100 mA at I <sub>F</sub> = 200 mA	V <sub>F</sub>	-	1	V
		-	1.25	
Total Capacitance at V <sub>R</sub> = 0, f = 1 MHz	C <sub>T</sub>	-	5	pF
Reverse Recovery Time at I <sub>F</sub> = I <sub>R</sub> = 30 mA, I <sub>RR</sub> = 0.1 X I <sub>R</sub> , R <sub>L</sub> = 100 Ω	t <sub>rr</sub>	-	50	ns

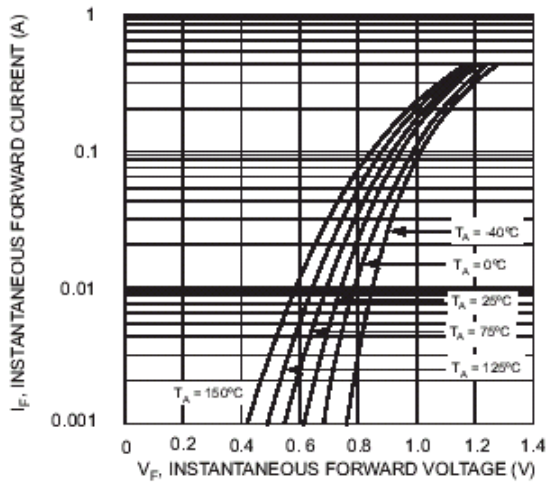


Fig. 1 Typical Forward Characteristics

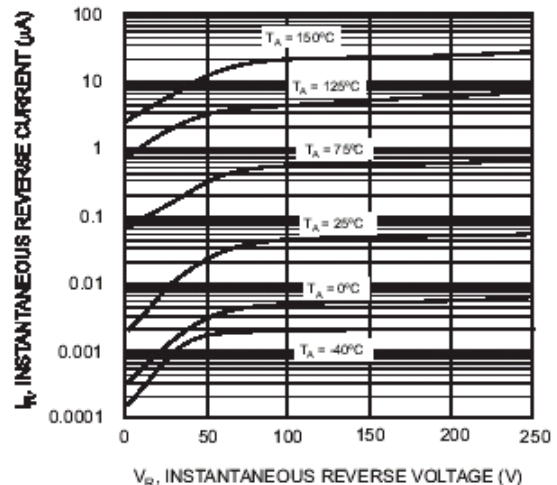


Fig. 2 Typical Reverse Characteristics

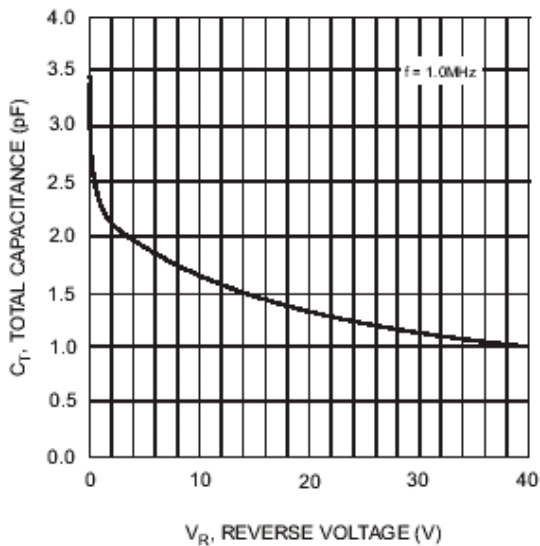


Fig. 3 Typical Capacitance vs. Reverse Voltage

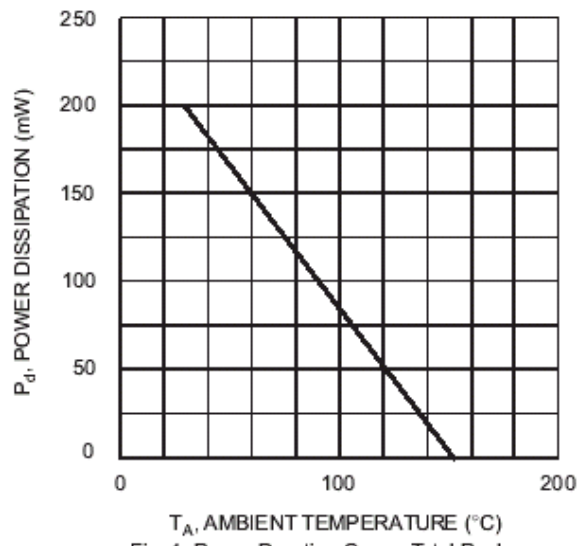
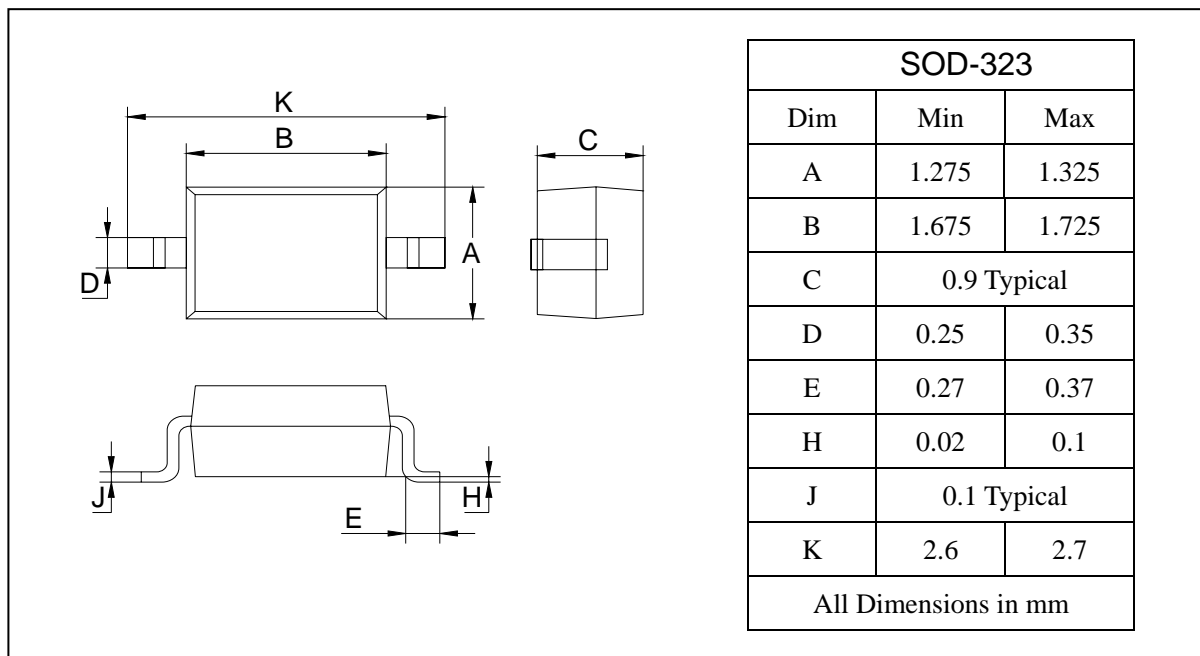


Fig. 4 Power Derating Curve, Total Package

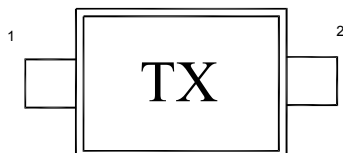
## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



Marking: TX



**Note:**

- (1) "T" is part number fixed
- (2) "X" : For model BAV19WS, the value is 1 ;  
For model BAV20WS, the value is 2 ;  
For model BAV21WS, the value is 3 ;